ON Semiconductor

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Power MOSFET 75 Amps, 60 Volts, Logic Level

N-Channel TO-220 and D²PAK

Designed for low voltage, high speed switching applications in power supplies, converters and power motor controls and bridge circuits.

Features

• Pb-Free Packages are Available

Typical Applications

- Power Supplies
- Converters
- Power Motor Controls
- Bridge Circuits

MAXIMUM RATINGS ($T_J = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	60	Vdc
Drain-to-Gate Voltage (R _{GS} = 10 M Ω)	V_{DGR}	60	Vdc
Gate-to-Source Voltage - Continuous - Non-Repetitive (t _p ≤ 10 ms)	V _{GS} V _{GS}	±20 ±15	Vdc
Drain Current $ \begin{array}{c} - \text{ Continuous } @ \ T_A = 25^{\circ}\text{C} \\ - \text{ Continuous } @ \ T_A = 100^{\circ}\text{C} \\ - \text{ Single Pulse } (t_p \! \leq \! 10 \ \mu\text{s}) \end{array} $	I _D I _D I _{DM}	75 50 225	Adc Apk
Total Power Dissipation @ T _A = 25°C Derate above 25°C Total Power Dissipation @ T _A = 25°C (Note 1)	P _D	214 1.4 2.4	W W/°C W
Operating and Storage Temperature Range	T _J , T _{stg}	-55 to +175	°C
Single Pulse Drain–to–Source Avalanche Energy – Starting $T_J = 25^{\circ}C$ ($V_{DD} = 50$ Vdc, $V_{GS} = 5.0$ Vdc, $L = 0.3$ mH $I_{L(pk)} = 75$ A, $V_{DS} = 60$ Vdc)	E _{AS}	844	mJ
Thermal Resistance – Junction–to–Case – Junction–to–Ambient (Note 1)	R _{θJC} R _{θJA}	0.7 62.5	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	TL	260	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

 When surface mounted to an FR4 board using minimum recommended pad size, (Cu Area 0.412 in²).

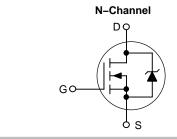


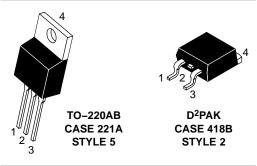
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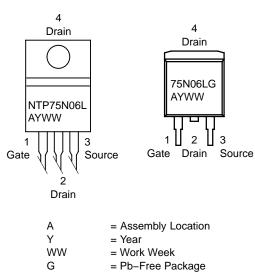
75 AMPERES, 60 VOLTS

 $R_{DS(on)} = 11 \text{ m}\Omega$





MARKING DIAGRAMS & PIN ASSIGNMENTS



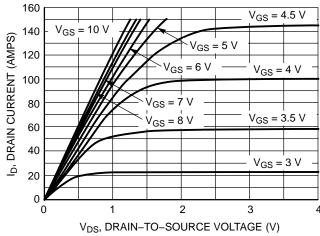
ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

C	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage (Note 2) (V _{GS} = 0 Vdc, I _D = 250 µAdc) Temperature Coefficient (Positive)		V _{(BR)DSS}	60 -	72 74	_ _	Vdc mV/°C
Zero Gate Voltage Drain Current $(V_{DS} = 60 \text{ Vdc}, V_{GS} = 0 \text{ Vdc})$ $(V_{DS} = 60 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, T_{J} = 150^{\circ}\text{C})$		I _{DSS}	- -	- -	10 100	μAdc
Gate-Body Leakage Current ($V_{GS} = \pm 15 \text{ Vdc}, V_{DS} = 0 \text{ Vdc}$	I _{GSS}	_	_	±100	nAdc
ON CHARACTERISTICS (Note	2)					
Gate Threshold Voltage (Note $(V_{DS} = V_{GS}, I_D = 250 \mu Adc)$ Threshold Temperature Coeffic	V _{GS(th)}	1.0	1.58 6.0	2.0	Vdc mV/°C	
Static Drain-to-Source On-Re (V _{GS} = 5.0 Vdc, I _D = 37.5 Ac	R _{DS(on)}	_	9.0	11	mΩ	
Static Drain-to-Source On-Vo $(V_{GS} = 5.0 \text{ Vdc}, I_D = 75 \text{ Adc}$ $(V_{GS} = 5.0 \text{ Vdc}, I_D = 37.5 \text{ Add}$	V _{DS(on)}	- -	0.75 0.61	0.99	Vdc	
Forward Transconductance (N	9FS	_	55	_	mhos	
DYNAMIC CHARACTERISTICS						
Input Capacitance	0/ 05 // 0 0 // 1	C _{iss}	_	3122	4370	pF
Output Capacitance	$(V_{DS} = 25 \text{ Vdc}, V_{GS} = 0 \text{ Vdc},$ f = 1.0 MHz)	C _{oss}	_	1029	1440	
Transfer Capacitance		C _{rss}	_	276	390	
SWITCHING CHARACTERISTIC	CS (Note 3)					
Turn-On Delay Time		t _{d(on)}	_	22	32	ns
Rise Time	$(V_{DD} = 30 \text{ Vdc}, I_D = 75 \text{ Adc},$	t _r	_	265	370	
Turn-Off Delay Time	$V_{GS} = 5.0 \text{ Vdc}, R_G = 9.1 \Omega) \text{ (Note 2)}$	t _{d(off)}	_	113	160	
Fall Time		t _f	_	170	240	
Gate Charge	$(V_{DS} = 48 \text{ Vdc}, I_{D} = 75 \text{ Adc}, V_{GS} = 5.0 \text{ Vdc}) \text{ (Note 2)}$	Q_{T}	-	66	92	nC
		Q ₁	_	9.0	-	
		Q_2	_	47	-	
SOURCE-DRAIN DIODE CHAR	ACTERISTICS					
Forward On-Voltage	$(I_S = 75 \text{ Adc}, V_{GS} = 0 \text{ Vdc}) \text{ (Note 2)}$ $(I_S = 75 \text{ Adc}, V_{GS} = 0 \text{ Vdc}, T_J = 150^{\circ}\text{C})$	V _{SD}		1.0 0.9	1.15 -	Vdc
Reverse Recovery Time		t _{rr}	_	70	-	ns
	$(I_S = 75 \text{ Adc}, V_{GS} = 0 \text{ Vdc}, \\ dI_S/dt = 100 \text{ A/}\mu\text{s}) \text{ (Note 2)}$	t _a	_	43	-	
		t _b	_	27	_	
Reverse Recovery Stored Charge		Q_{RR}	_	0.16	-	μC

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
 Switching characteristics are independent of operating junction temperatures.



V_{DS}, DRAIN-TO-SOURCE VOLTAGE (V)

Figure 1. On-Region Characteristics

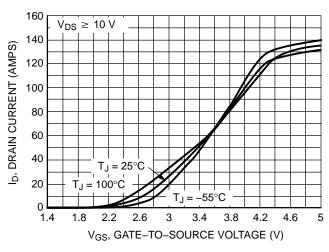


Figure 2. Transfer Characteristics

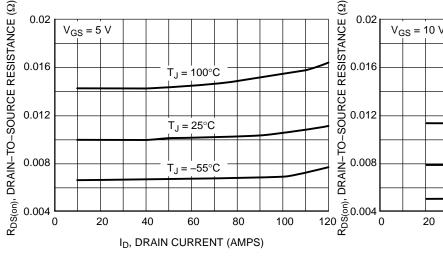


Figure 3. On–Resistance vs. Gate–to–Source Voltage

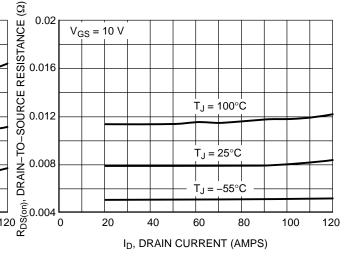


Figure 4. On-Resistance vs. Drain Current and Gate Voltage

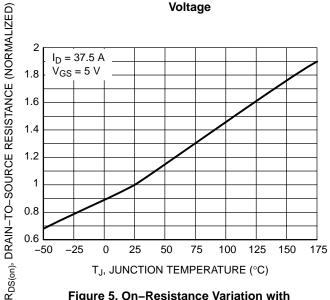


Figure 5. On–Resistance Variation with Temperature

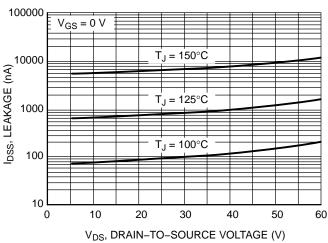


Figure 6. Drain-to-Source Leakage Current vs. Voltage

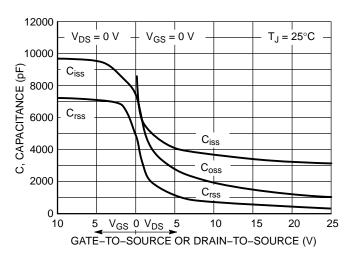


Figure 7. Capacitance Variation

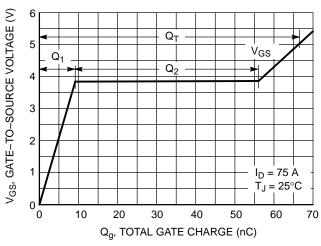


Figure 8. Gate-to-Source and Drain-to-Source Voltage vs. Total Charge

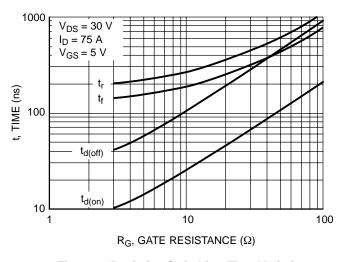


Figure 9. Resistive Switching Time Variations vs. Gate Resistance

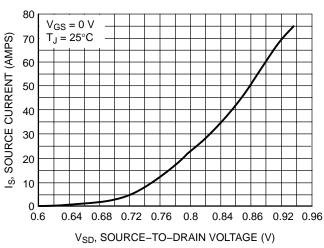


Figure 10. Diode Forward Voltage vs. Current

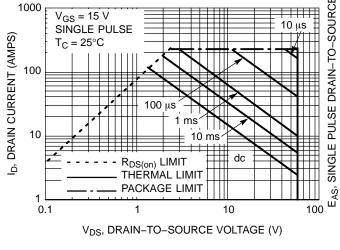


Figure 11. Maximum Rated Forward Biased Safe Operating Area

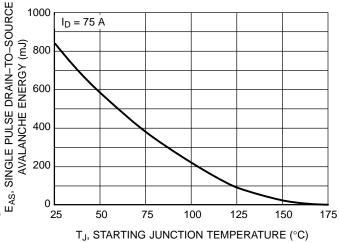


Figure 12. Maximum Avalanche Energy vs. Starting Junction Temperature

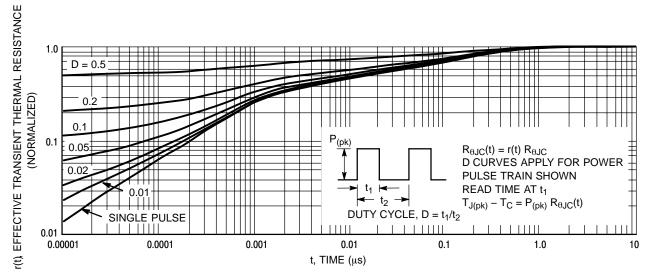


Figure 13. Thermal Response

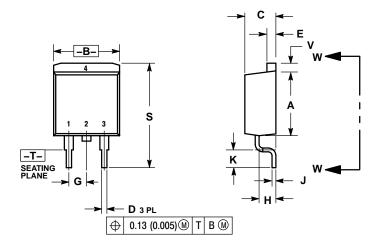
ORDERING INFORMATION

Device	Package	Shipping [†]
NTP75N06L	TO-220AB	50 Units / Rail
NTB75N06L	D ² PAK	50 Units / Rail
NTB75N06LG	D ² PAK (Pb-Free)	50 Units / Rail
NTB75N06LT4	D ² PAK	800 Units / Tape & Reel
NTB75N06LT4G	D ² PAK (Pb-Free)	800 Units / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

D²PAK CASE 418B-04 ISSUE J

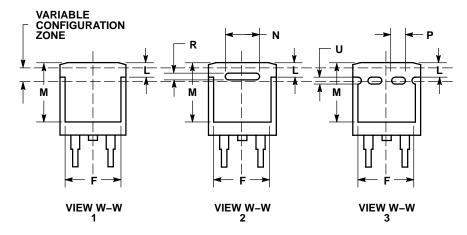




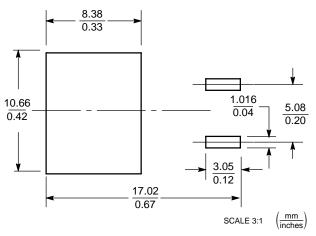
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 418B-01 THRU 418B-03 OBSOLETE, NEW STANDARD 418B-04.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.340	0.380	8.64	9.65	
В	0.380	0.405	9.65	10.29	
С	0.160	0.190	4.06	4.83	
D	0.020	0.035	0.51	0.89	
E	0.045	0.055	1.14	1.40	
F	0.310	0.350	7.87	8.89	
G	0.100 BSC		2.54 BSC		
Н	0.080	0.110	2.03	2.79	
J	0.018	0.025	0.46	0.64	
K	0.090	0.110	2.29	2.79	
L	0.052	0.072	1.32	1.83	
М	0.280	0.320	7.11	8.13	
N	0.197 REF		5.00 REF		
Р	0.079 REF		2.00 REF		
R	0.039	REF	0.99 REF		
S	0.575	0.625	14.60	15.88	
V	0.045	0.055	1 14	1 40	

- STYLE 2:
 PIN 1. GATE
 2. DRAIN
 3. SOURCE
 4. DRAIN



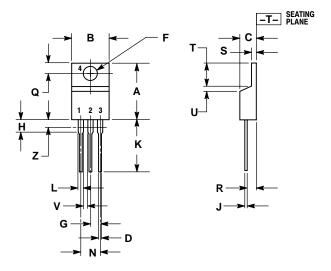
SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AA**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI
- CONTROLLING DIMENSION: INCH.
- DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

STYLE 5: PIN 1.

GATE DRAIN 2.

3. SOURCE

DRAIN

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